



MMIC SURFACE MOUNT

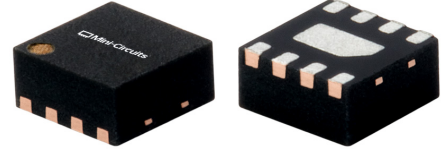
Low Noise Amplifier

TSS-43ULN+

50Ω 500 to 4000 MHz Shutdown Feature

THE BIG DEAL

- Low Noise Figure, Typ. 0.4 dB
- High Gain, Typ. 19 dB
- High OIP3, Typ. +36.1 dBm
- Fast Shutdown Feature, 14.4 ns
- Single Supply Voltage, +5 V at 59 mA
- 2x2 mm 8-Lead QFN-style Package

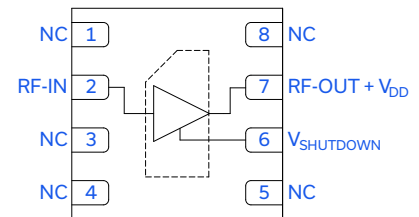


Generic photo used for illustration purposes only

APPLICATIONS

- Cellular Infrastructure
- Satellite Communications
- Radar, EW, and ECM Defense Systems

FUNCTIONAL DIAGRAM (TOP VIEW)



PRODUCT OVERVIEW

The TSS-43ULN+ is a pHEMT-based wideband, ultra-low noise MMIC amplifier with high P1dB, high IP3, and voltage-controlled shutdown capability. Operating from 500 to 4000 MHz, this amplifier features typical 0.4 dB noise figure, 19 dB gain, +23.7 dBm P1dB, and +36.1 dBm OIP3. This combination of characteristics makes it ideal for sensitive receiver applications. TSS-43ULN+ operates on a single +5 V supply and comes in a small, low profile, 2x2 mm QFN-style package for ease of integration into dense circuit board layouts.

KEY FEATURES

Features	Advantages
Ultra-Low Noise Figure, Typ. 0.4 dB	Operating from a single supply, this ultra-low noise MMIC enables low system noise figure performance, without the need for complicated discrete-based solutions.
High Gain, Typ. 19 dB	The MMIC amplifier's high gain enables fewer system components in receiver signal chains.
Shutdown Feature	A voltage-controlled shutdown feature allows the part to be quickly disabled to conserve power when not in use.
High Dynamic Range <ul style="list-style-type: none"> • Gain, Typ. 19 dB • OIP3, Typ. +36.1 dBm • P1dB, Typ. +23.7 dBm 	The MMIC amplifier's unique combination of low noise figure, high gain, high P1dB, and high OIP3 enables optimum performance in sensitive high dynamic range receivers.
2x2 mm 8-Lead QFN-Style Package	Small footprint saves space in dense layouts while providing low inductance, repeatable transitions, and excellent thermal contact to the PCB. Industry standard packaging allows for ease of assembly in high volume manufacturing processes.



MMIC SURFACE MOUNT

Low Noise Amplifier

TSS-43ULN+

Mini-Circuits

50Ω 500 to 4000 MHz Shutdown Feature

ELECTRICAL SPECIFICATIONS¹ AT +25°C AND Z₀ = 50Ω UNLESS NOTED OTHERWISE

Parameter	Condition (MHz)	Amplifier - ON			Amplifier - ON	Amplifier - OFF ²	Units
		V _{DD} = +5 V (V _{SHUTDOWN} = 0 V)			V _{DD} = +3 V (V _{SHUTDOWN} = 0 V)	V _{DD} = +5 V (V _{SHUTDOWN} = +5 V)	
		Min.	Typ.	Max.	Typ.	Typ.	
Frequency Range		500		4000	500-4000	500-4000	MHz
Gain	500	27.4	28.7		26.8	-42.3	dB
	1000	23.1	24.4		23.0	-44.3	
	2000	17.7	19.0		17.8	-31.7	
	3000	14.6	15.8		14.6	-23.5	
	4000	12.3	13.9		12.6	-18.0	
Input Return Loss	500		5		4		dB
	1000		8		7		
	2000		11		10		
	3000		12		10		
	4000		11		9		
Output Return Loss	500		5		5		dB
	1000		6		7		
	2000		6		7		
	3000		7		9		
	4000		9		11		
Isolation	500-4000		28.6		26.8	32.3	dB
Output Power at 1 dB Compression (P1dB)	500		+22.9		+18.0		dBm
	1000		+23.3		+18.3		
	2000		+23.7		+18.8		
	3000		+24.0		+19.1		
	4000		+23.6		+18.7		
Output Third-Order Intercept Point (P _{OUT} = +4 dBm/Tone)	500		+33.6		+25.8		dBm
	1000		+34.6		+26.2		
	2000		+36.1		+26.6		
	3000		+37.4		+27.2		
	4000		+38.2		+27.0		
Noise Figure ³	500		0.2		0.2		dB
	1000		0.3		0.3		
	2000		0.4		0.4		
	3000		0.4		0.5		
	4000		0.7		0.8		
ON Time (50% V _{CTRL} to 90% RF)			32.1				ns
RISE Time (10% RF to 90% RF)			6.3				ns
FALL Time (90% RF to 10% RF)			6.3				ns
OFF Time (50% V _{CTRL} to 10% RF)			14.4				ns
Device Operating Voltage (V _{DD})		+4.75	+5	+5.25	+3	+5	V
Device Operating Current (I _{DD}) ⁴			59		30	3	mA
Device Shutdown Voltage (V _{SHUTDOWN})			0		0	+5	V
Device Shutdown Current (I _{SHUTDOWN})			0.1		0.02	33	μA
Device Current Variation vs. Temperature ⁵			0.007		0.007		mA/°C
Device Current Variation vs. Voltage ⁶			0.0144		0.0144		mA/mV

1. Tested in Mini-Circuits Characterization Test/Evaluation Board TB-TSS-43ULNC+. See Figure 2. Board loss de-embedded to the device.

2. Performance is comparable when V_{SHUTDOWN} = +5 V or +3 V when amplifier is OFF.

3. Typical value verified and set by averaging performance across multiple measurement setups.

4. Current at P_N = -25 dBm. Increases to 105 mA at P1dB.

5. (Current at +105°C - Current at -45°C) / (+150°C)

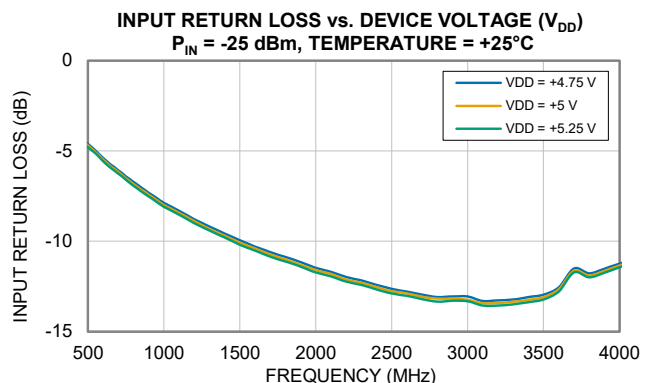
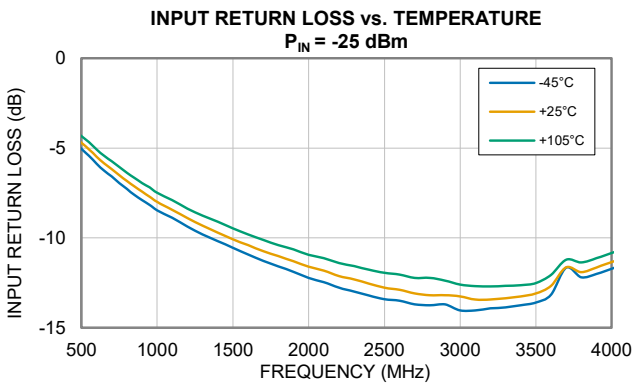
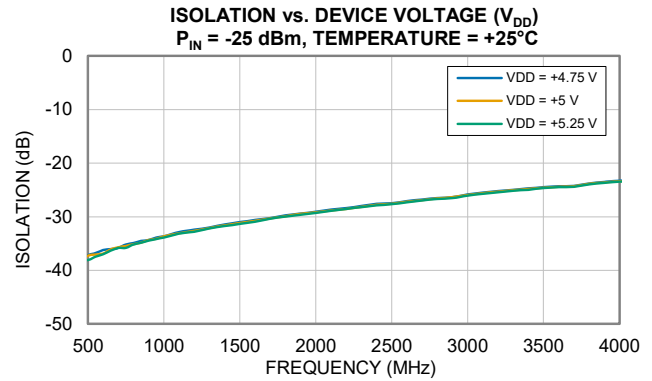
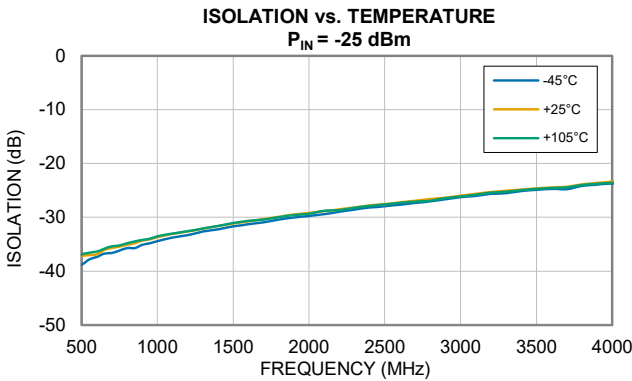
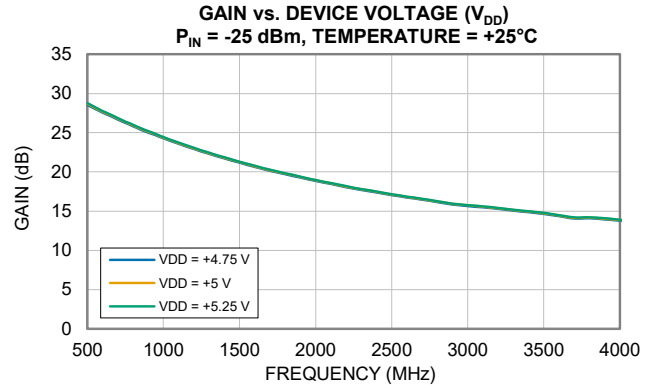
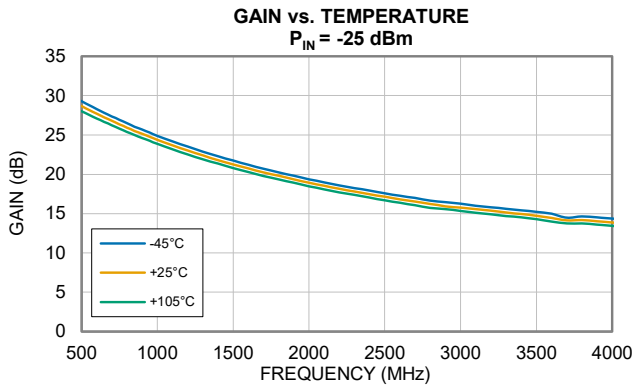
6. (Current at +5.25 V - Current at +4.75 V) / (+0.5 V)





TYPICAL PERFORMANCE GRAPHS

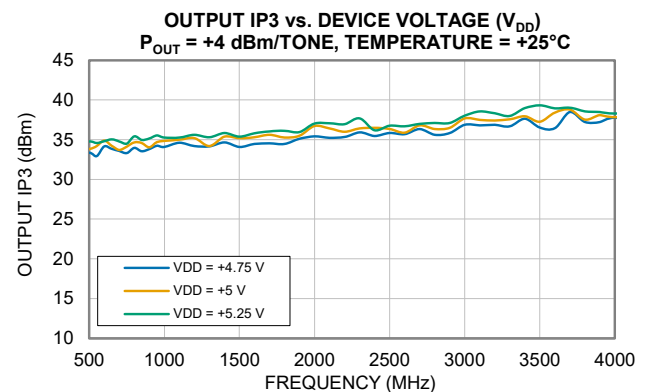
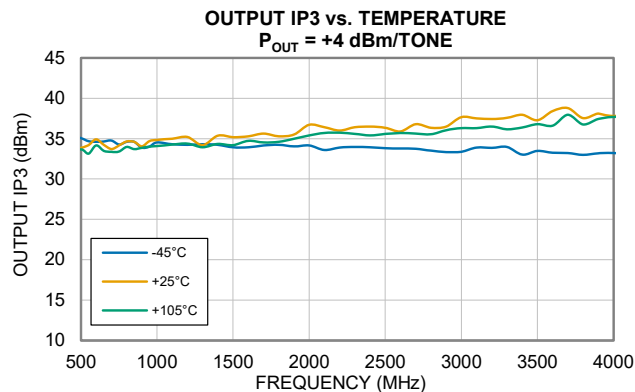
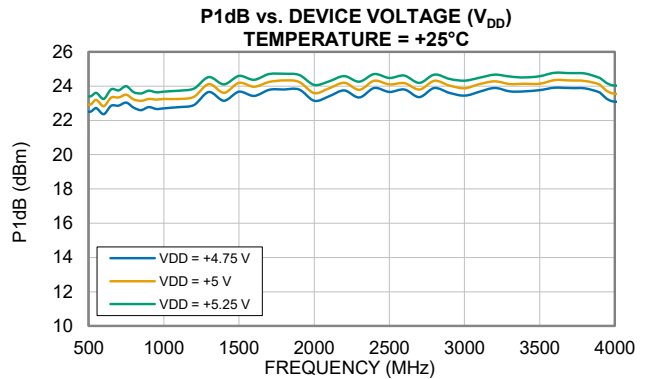
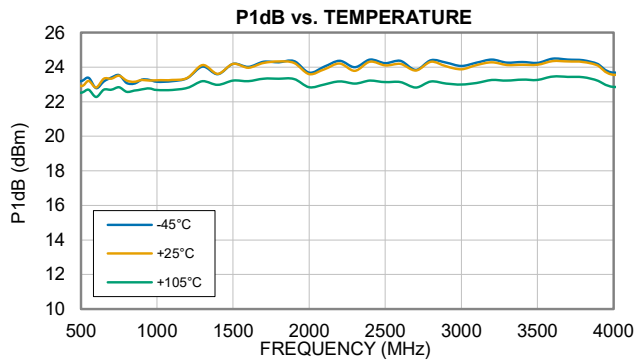
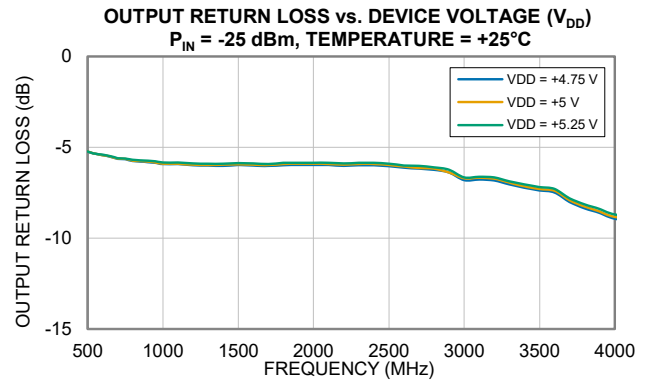
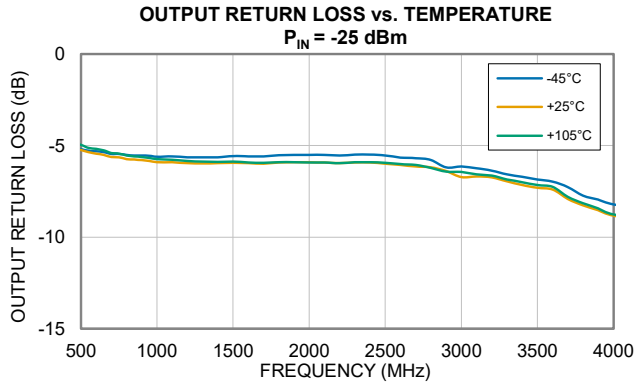
Note: The following data was taken on the Mini-Circuits Characterization Test Board TB-TSS-43ULNC+ (Figure 2). All data taken at nominal condition of $V_{DD} = +5$ V and at $V_{SHUTDOWN} = 0$ V unless noted otherwise.





TYPICAL PERFORMANCE GRAPHS

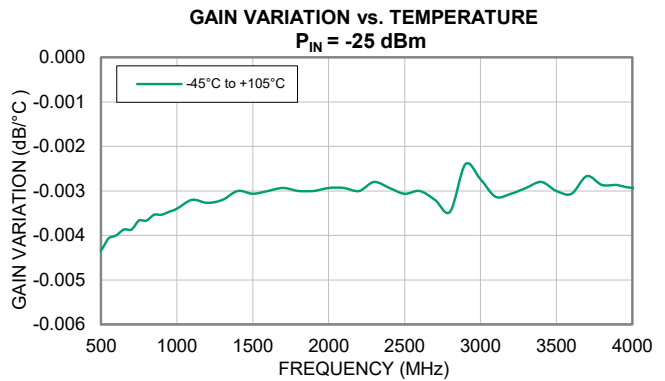
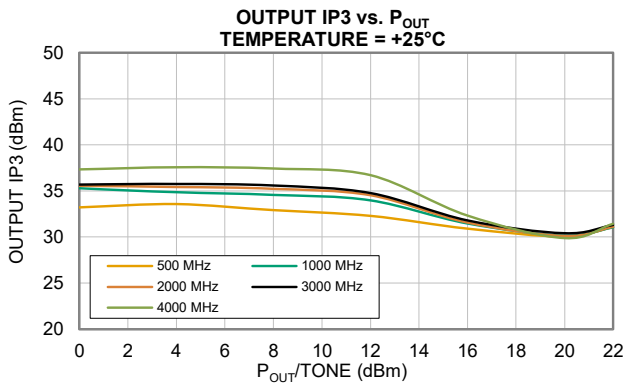
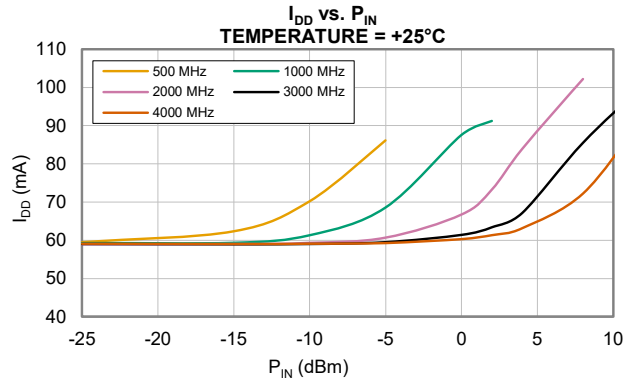
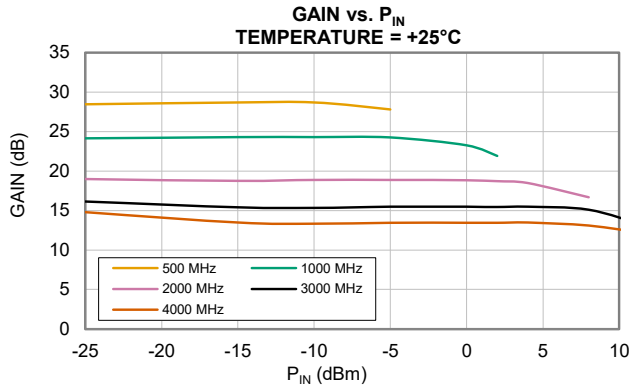
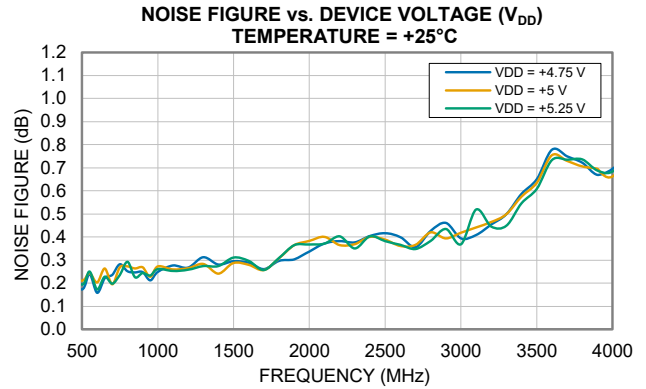
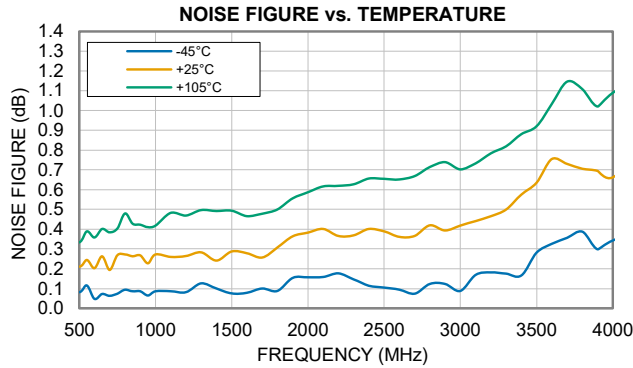
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TYPICAL PERFORMANCE GRAPHS

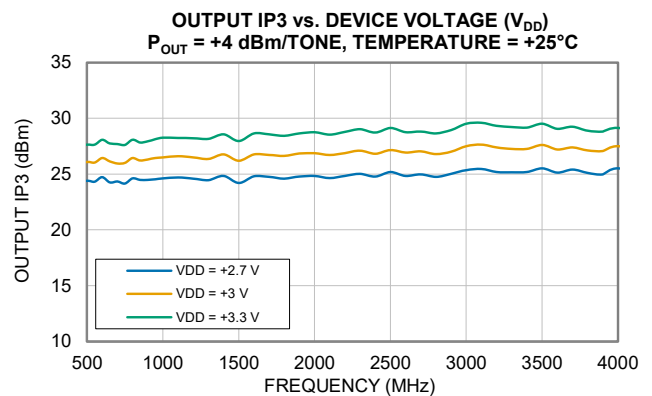
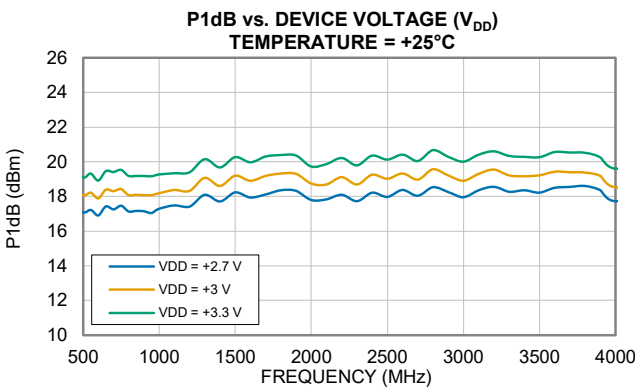
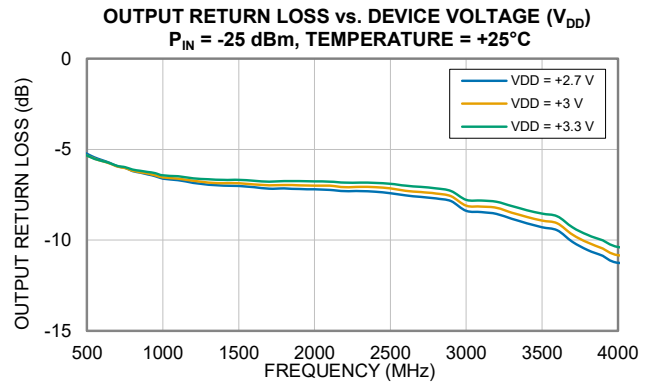
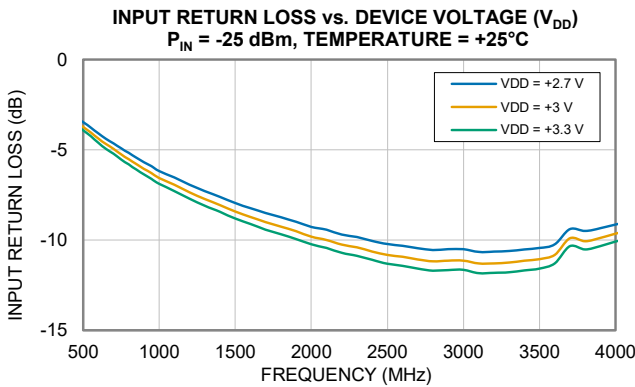
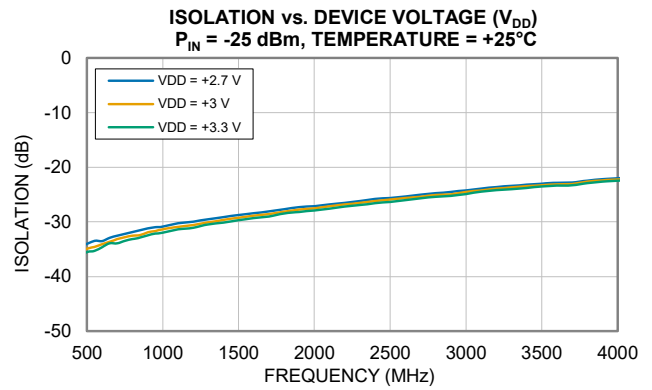
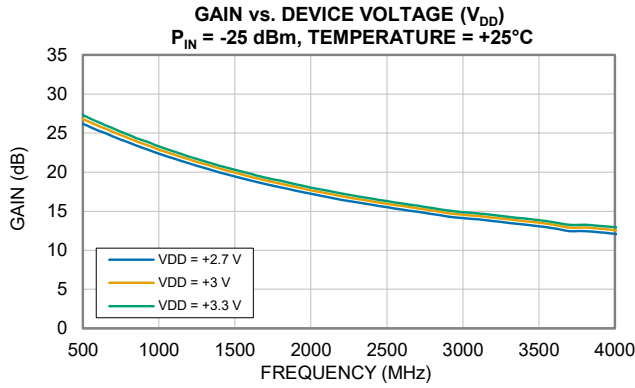
Note: The following data was taken on the Mini-Circuits Characterization Test Board TB-TSS-43ULNC+ (Figure 2). All data taken at nominal condition of $V_{DD} = +5\text{ V}$ and at $V_{SHUTDOWN} = 0\text{ V}$ unless noted otherwise.





TYPICAL LOW VOLTAGE PERFORMANCE GRAPHS

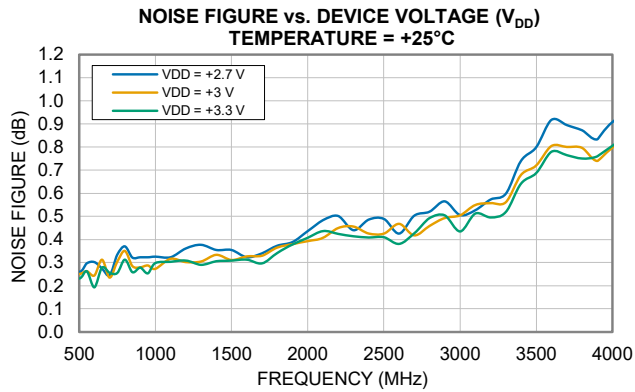
Note: The following data was taken on the Mini-Circuits Characterization Test Board TB-TSS-43ULNC+ (Figure 2). All data taken at $V_{SHUTDOWN} = 0\text{ V}$ unless noted otherwise.





TYPICAL LOW VOLTAGE PERFORMANCE GRAPHS

Note: The following data was taken on the Mini-Circuits Characterization Test Board TB-TSS-43ULNC+ (Figure 2). All data taken at $V_{SHUTDOWN} = 0\text{ V}$ unless noted otherwise.



ABSOLUTE MAXIMUM RATINGS⁷

Parameter	Ratings
Operating Temperature	-45°C to +105°C
Storage Temperature	-65°C to +150°C
Total Power Dissipation	1.2 W
Junction Temperature ⁸	+150°C
Input Power (CW)	
$V_{DD} = +5\text{ V}$ & $V_{SHUTDOWN} = 0\text{ V}$	+21 dBm
$V_{DD} = +3\text{ V}$ & $V_{SHUTDOWN} = 0\text{ V}$	+21 dBm
DC Voltage on RF-OUT & V_{DD}	
$V_{SHUTDOWN} = 0\text{ V}$	+10 V
$V_{SHUTDOWN} = +5\text{ V}$	+10 V
DC Voltage on RF-IN	
$V_{SHUTDOWN} = 0\text{ V}$	+1 V
$V_{SHUTDOWN} = +5\text{ V}$	+1 V
DC Voltage on $V_{SHUTDOWN}$	
$V_{DD} = 0\text{ V}$	+10 V
$V_{DD} = +5\text{ V}$	+10 V
DC Current on RF-OUT & V_{DD}	
$V_{SHUTDOWN} = 0\text{ V}$	130 mA
$V_{SHUTDOWN} = +5\text{ V}$	10 mA
DC Current $V_{SHUTDOWN}$	
$V_{SHUTDOWN} = 0\text{ V}$	3 mA
$V_{SHUTDOWN} = +5\text{ V}$	6 mA

7. Permanent damage may occur if any of these limits are exceeded. Maximum ratings are not intended for continuous normal operation.

8. Peak temperature on top of Die.

POWER ON / POWER OFF LOGIC

Amplifier State	V_{DD}			$V_{SHUTDOWN}$		
	Min	Typ.	Max	Min	Typ.	Max
Amplifier - ON ($V_{DD} = +5\text{ V}$)	+2.7 V	+5 V	+5.25 V	0 V	0 V	+1 V
Amplifier - OFF ($V_{DD} = +5\text{ V}$)				+1.1 V	+5 V	+5.25 V
Amplifier - ON ($V_{DD} = +3\text{ V}$)	+2.7 V	+3 V	+5.25 V	0 V	0 V	+1 V
Amplifier - OFF ($V_{DD} = +3\text{ V}$)				+1.1 V	+3 V	+5.25 V

THERMAL RESISTANCE

Parameter	Ratings
Thermal Resistance (θ_{JC}) ⁹	37.7°C/W

9. θ_{JC} = (Hot Spot Temperature on Die - Temperature at Ground Lead)/Dissipated Power

ESD RATING

	Class	Voltage Range	Reference Standard
HBM	1B	500 V to < 1000 V	ANSI/ESDA/JEDEC JS-001-2023
CDM	C3	> 1000 V	ANSI/ESDA/JEDEC JS-002-2022



ESD HANDLING PRECAUTION: This device is designed to be Class 1B for HBM. Static charges may easily produce potentials higher than this with improper handling and can discharge into DUT and damage it. As a preventive measure Industry standard ESD handling precautions should be used at all times to protect the device from ESD damage.

MSL RATING

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020E /JEDEC J-STD-033C



FUNCTIONAL DIAGRAM (TOP VIEW)

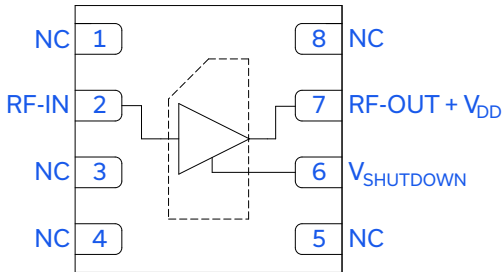


Figure 1. TSS-43ULN+ Functional Diagram

PAD DESCRIPTION

Function	Pad Number	Description (Refer to Figure 2)
RF-OUT + V _{DD}	7	RF-OUT + V _{DD} Pad connects to RF-Output port and voltage input port, V _{DD} .
V _{SHUTDOWN}	6	DC Input Pad connects to voltage input port, V _{SHUTDOWN} .
RF-IN	2	RF-IN Pad connects to RF-Input port.
NC	1,3-5 & 8	Not used internally. May be connected to ground or left floating. All pins but pin 1 are grounded on evaluation board.
GND	Paddle	Connects to ground.

EVALUATION BOARD

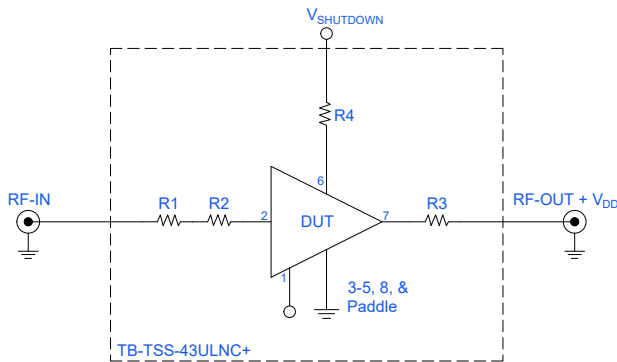


Figure 2. TSS-43ULN+ Evaluation and Application Circuit

Electrical Parameters and Conditions

Gain, Return Loss, Output Power at 1 dB Compression (P1dB), Output IP3 (OIP3), and Noise Figure measured using N5242A PNA-X microwave network analyzer.

Conditions:

1. Gain and Return Loss: P_{IN} = -25 dBm
2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, +4 dBm/tone at output.

Power ON/Power OFF Sequence:

Caution: Permanent damage to the device will occur if the Power ON and Power OFF sequences are not followed.

POWER ON:

1. Set V_{DD} = +5 V.
2. Set V_{SHUTDOWN} = 0 V for ON mode or V_{SHUTDOWN} = +5 V for OFF mode.
3. Turn on V_{DD}.
4. Turn on V_{SHUTDOWN}.
5. Apply RF signal.

POWER OFF:

1. Turn off RF signal.
2. Turn off V_{SHUTDOWN}.
3. Turn off V_{DD}.

Component	Size	Value	Part Number	Manufacturer
R1-R4	0402	0Ω	RK73Z1ETTP	KOA Speer



APPLICATION CIRCUIT

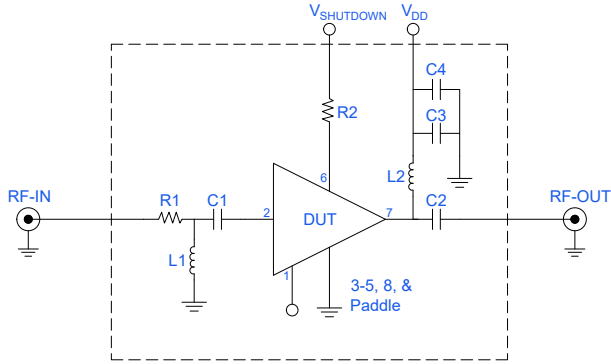


Figure 3. TSS-43ULN+ 1900-2700 MHz Application Circuit

Electrical Parameters and Conditions

Gain, Return Loss, Output Power at 1 dB Compression (P1dB), Output IP3 (OIP3), and Noise Figure measured using N5242A PNA-X microwave network analyzer.

Conditions:

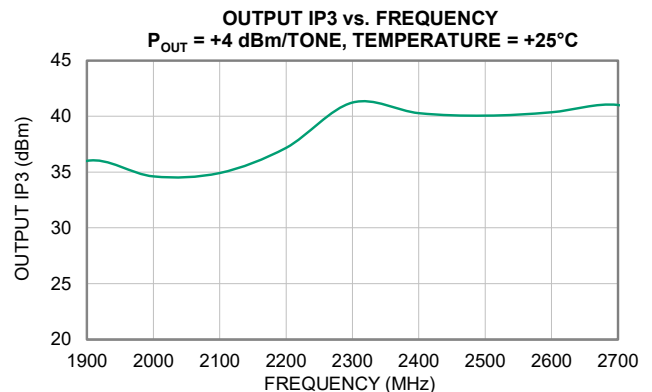
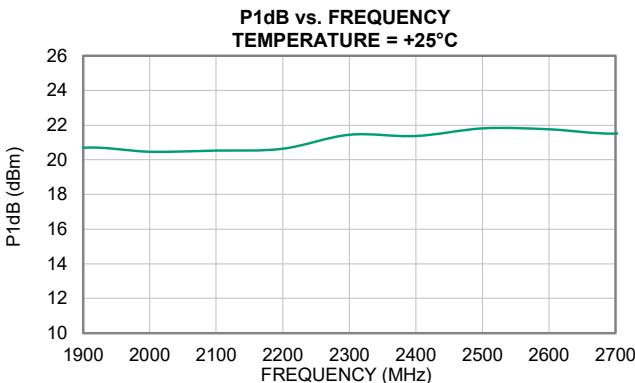
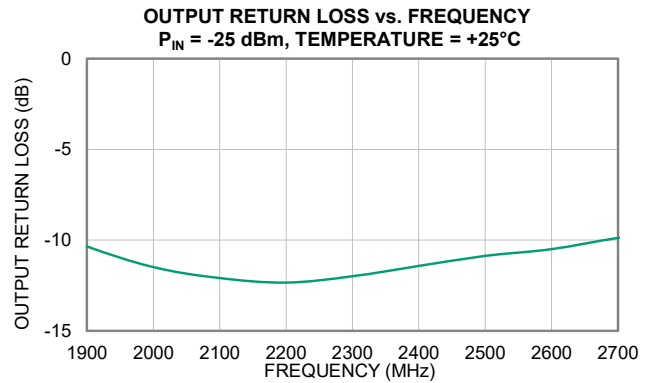
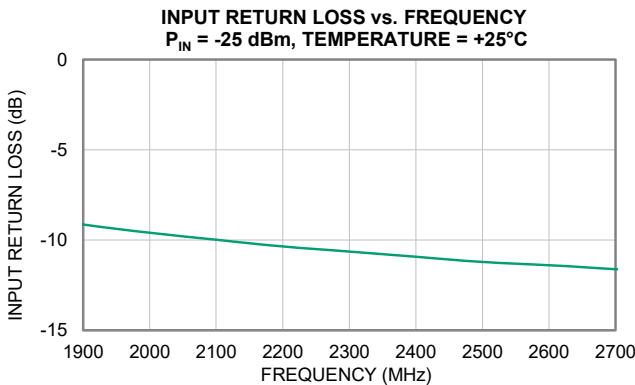
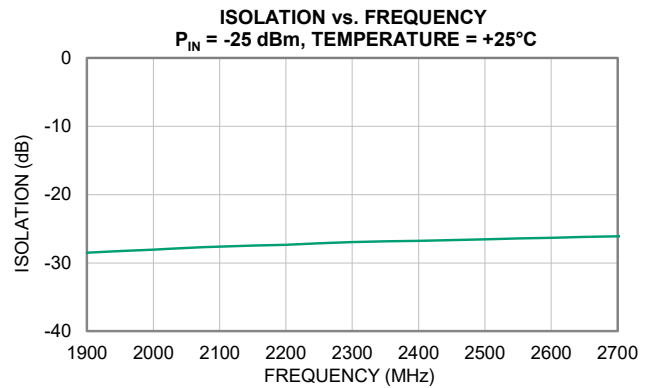
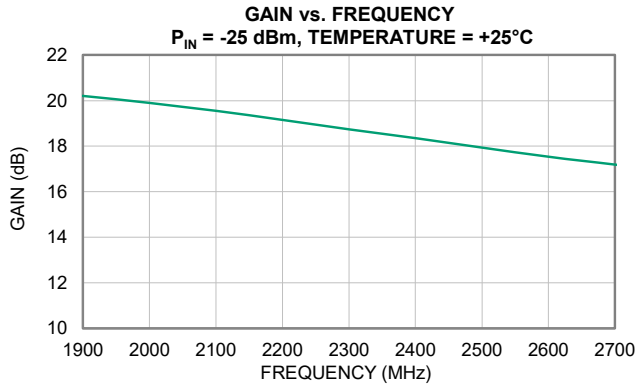
- 3. Gain and Return Loss: $P_{IN} = -25$ dBm
- 4. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, +4 dBm/tone at output.

Component	Size	Value	Part Number	Manufacturer
R1-R2	0402	0Ω	RK73Z1ETTP	KOA Speer
C1	0402	3.6 pF	GJM1555C1H3R6CB01	Murata
C2	0402	3 pF	GJM1555C1H3R0CB01	Murata
C3	0402	100 pF	GRM1555C1H101GA01D	Murata
C4	0402	1 μF	GRM155Z71A105KE01J	Murata
L1	0402	5.6 nH	LQG15HS5N6B02	Murata
L2	0402	2.2 nH	LQG15HS2N2B02	Murata



TYPICAL MATCHING TEST BOARD PERFORMANCE GRAPHS

Note: The following data was taken on the Mini-Circuits 1900-2700 MHz Matched Characterization Test Board (Figure 3). All data taken at nominal condition of $V_{DD} = +5\text{ V}$ and at $V_{SHUTDOWN} = 0\text{ V}$.





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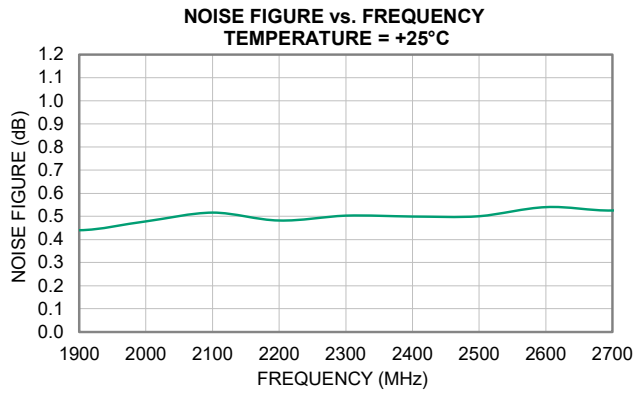
TSS-43ULN+

Mini-Circuits

50Ω 500 to 4000 MHz Shutdown Feature

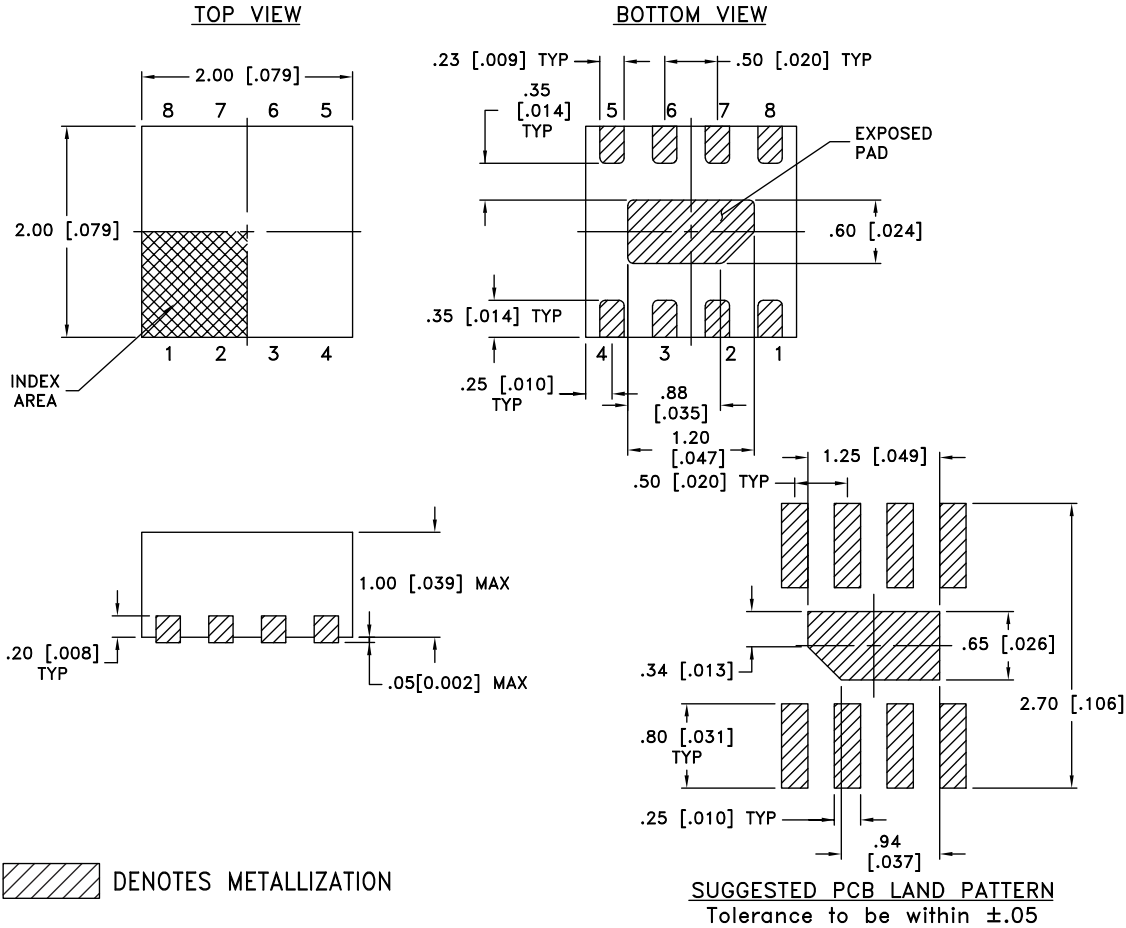
TYPICAL MATCHING TEST BOARD PERFORMANCE GRAPHS

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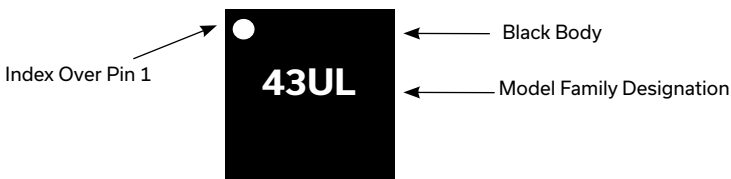


CASE STYLE DRAWING



Weight: 0.006 grams
Dimensions are in mm [Inches]. Tolerances: 2 Pl. ± 0.13 mm

PRODUCT MARKING



Marking may contain other features or characters for internal lot control.



MMIC SURFACE MOUNT

Low Noise Amplifier

TSS-43ULN+

50Ω 500 to 4000 MHz Shutdown Feature

ADDITIONAL DETAILED INFORMATION IS AVAILABLE ON OUR DASHBOARD

[CLICK HERE](#)

Performance Data & Graphs	Data Graphs S-Parameter (S2P Files) Data Set (.zip file)
Case Style	MC1631-1. Plastic package, exposed paddle, Lead Finish: Matte-Tin
RoHS Status	Compliant
Tape & Reel Standard Quantities Available on Reel	F66 7" Reels with 20, 50, 100, 200, 500, 1000, 2000, or 3000 devices
Suggested Layout for PCB Design	PL-844
Evaluation Board	TB-TSS-43ULNC+ Gerber File
Environmental Ratings	ENV08T1

NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuits' applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/terms/viewterm.html

